

## FAST RECOVERY RECTIFIER DIODES

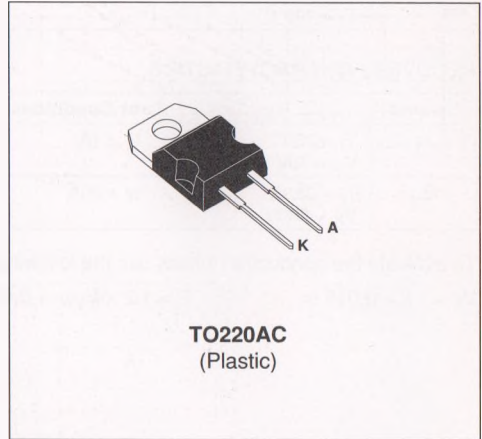
- HIGH VOLTAGE CAPABILITY
- FAST AND SOFT RECOVERY
- THE SPECIFICATIONS AND CURVES ENABLE THE DETERMINATION OF THE  $t_{rr}$  AND  $I_{RM}$  AT 100°C UNDER USERS CONDITIONS

### APPLICATIONS

- MOTOR CONTROLS AND CONVERTERS
- SWITCHMODE POWER SUPPLIES

### DESCRIPTION

Fast recovery rectifiers suited for applications in combination with superswitch transistors



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{FRM}$	Repetitive Peak Forward Current	$t_p \leq 20\mu s$	120	A
$I_{F(RMS)}$	RMS Forward Current		16	A
$I_{F(AV)}$	Average Forward Current	$T_c = 100^\circ C$ $\delta = 0.5$	10	A
$I_{FSM}$	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	120	A
$P_{Tot}$	Power Dissipation	$T_c = 100^\circ C$	20	W
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 40 to 150	°C

Symbol	Parameter	ESM 765-					Unit
		100	200	400	600	800	
$V_{RRM}$	Repetitive Peak Reverse Voltage	100	200	400	600	800	V
$V_{RSM}$	Non Repetitive Peak Reverse Voltage	100	200	400	600	800	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case	2	°C/W

## ELECTRICAL CHARACTERISTICS

## STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub>	T <sub>j</sub> = 25°C	V <sub>R</sub> = V <sub>RRM</sub>			20	μA
	T <sub>j</sub> = 100°C				1	mA
V <sub>F</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 10A			1.4	V
	T <sub>j</sub> = 100°C				1.35	

## RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t <sub>rr</sub>	T <sub>j</sub> = 25°C V <sub>R</sub> = 30V	I <sub>F</sub> = 1A	di <sub>F</sub> /dt = - 15A/μs			300	ns
Q <sub>rr</sub>	T <sub>j</sub> = 25°C V <sub>R</sub> = 200V	I <sub>F</sub> = 10A	di <sub>F</sub> /dt = - 50A/μs		2.3		μC

To evaluate the conduction losses use the following equations :

$$V_F = 1.2 + 0.015 I_F$$

$$P = 1.2 \times I_{F(AV)} + 0.015 I_F^2 (RMS)$$

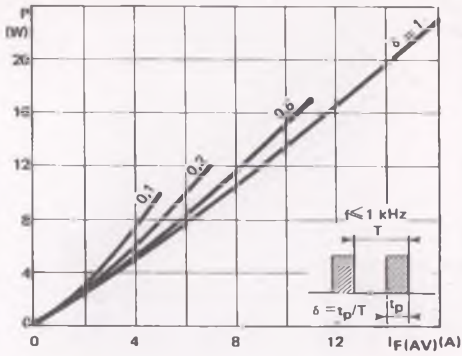


FIGURE 1: Low frequency power losses versus average current

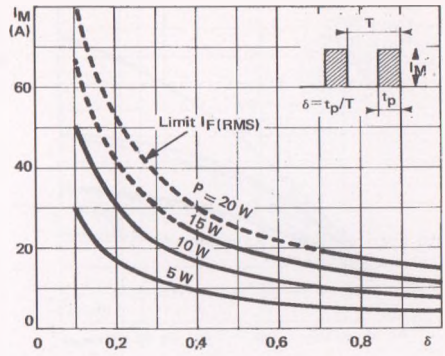


FIGURE 2: Peak current versus form factor

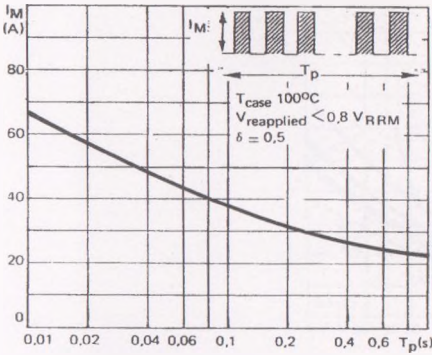


FIGURE 3: Non repetitive peak surge current versus overload duration

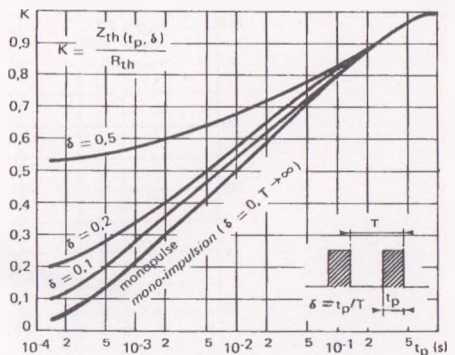


FIGURE 4: Thermal impedance versus pulse width

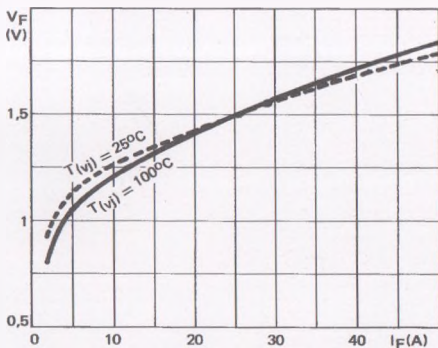


FIGURE 5: Forward voltage drop versus forward current

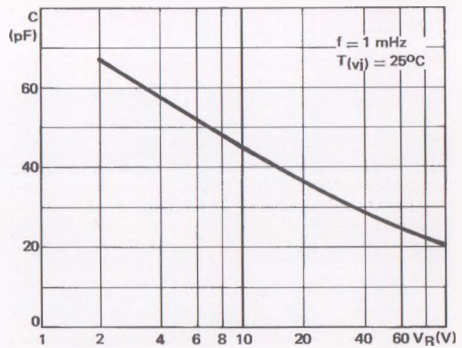


FIGURE 6: Capacitance versus applied reverse voltage

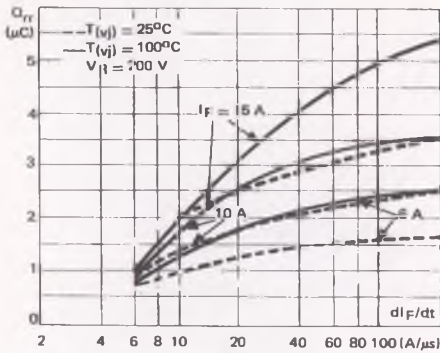


FIGURE 7: Recovery charge versus  $dI_F/dt$

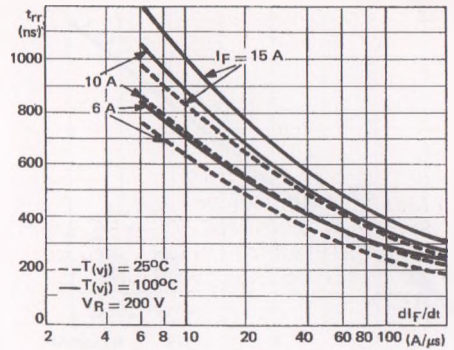


FIGURE 8: Recovery time versus  $dI_F/dt$

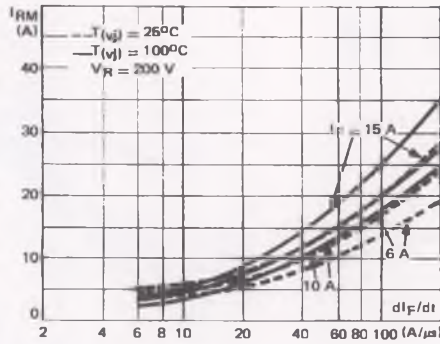


FIGURE 9: Peak reverse current versus  $dI_F/dt$